

RQJ0204XGDQA

Silicon P Channel MOS FET
Power Switching

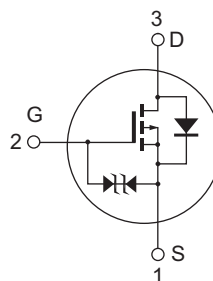
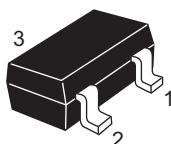
R07DS0293EJ0500
Rev.5.00
Jan 10, 2014

Features

- Low on-resistance
 $R_{DS(on)} = 219 \text{ m}\Omega$ typ ($V_{GS} = -4.5 \text{ V}$, $I_D = -0.8 \text{ A}$)
- Low drive current
- High speed switching
- 2.5 V gate drive

Outline

RENESAS Package code: PLSP0003ZB-A
(Package name: MPAK)



1. Source
2. Gate
3. Drain

Note: Marking is "XG".

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	-20	V
Gate to source voltage	V_{GSS}	+8 / -12	V
Drain current	I_D	-1.6	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	-4.0	A
Body - drain diode reverse drain current	I_{DR}	-1.6	A
Channel dissipation	P_{ch} ^{Note2}	0.8	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)

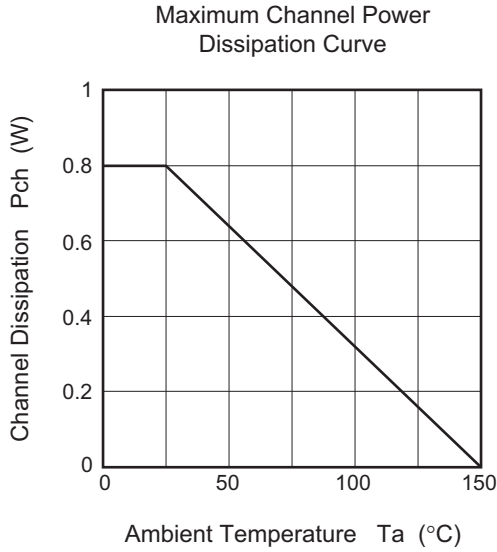
Electrical Characteristics

(Ta = 25°C)

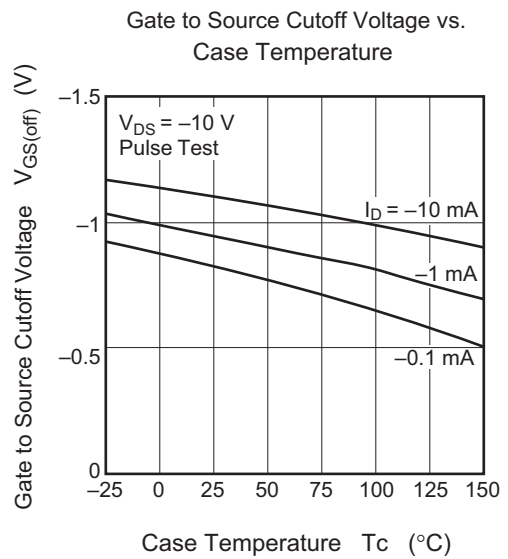
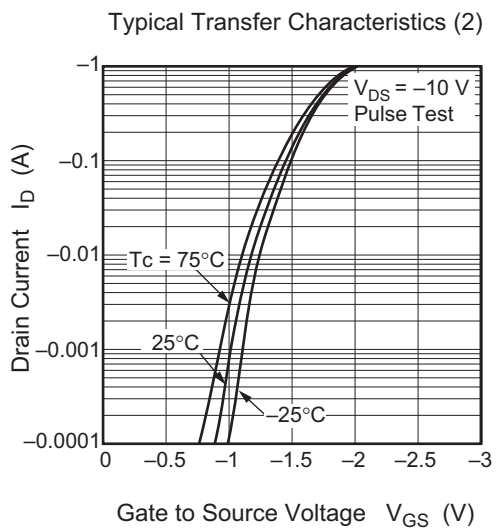
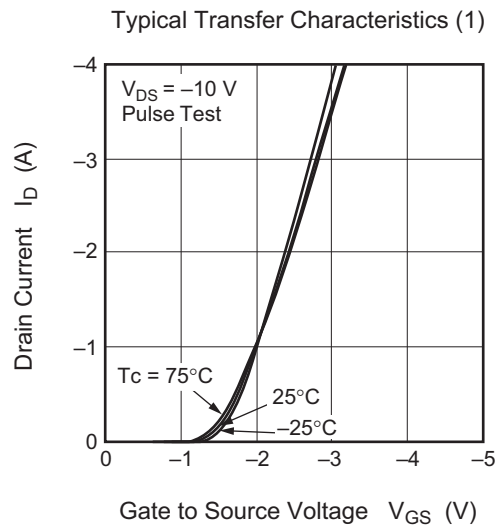
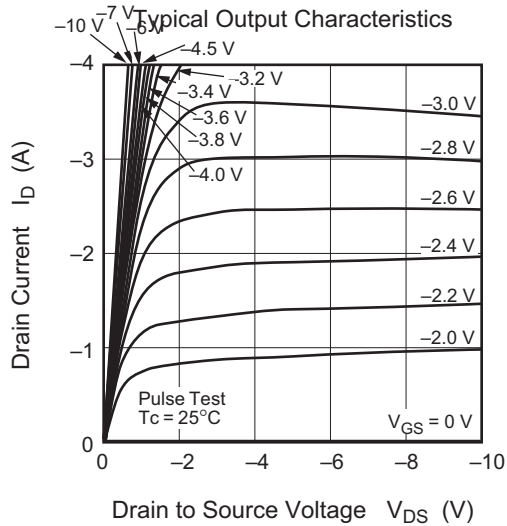
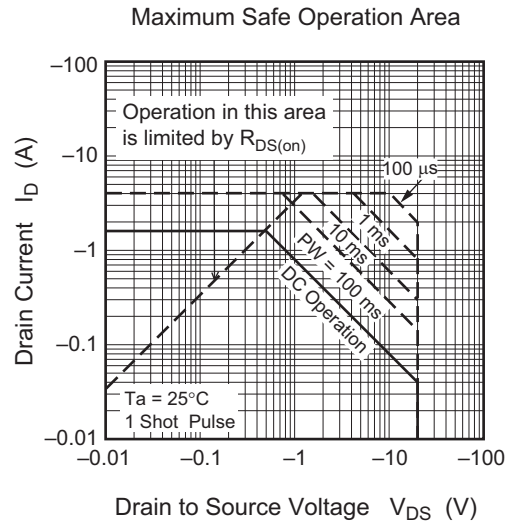
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-20	—	—	V	$I_D = -10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	+8	—	—	V	$I_G = +100 \text{ } \mu\text{A}$, $V_{DS} = 0$
	$V_{(BR)GSS}$	-12	—	—	V	$I_G = -100 \text{ } \mu\text{A}$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	+10	μA	$V_{GS} = +6 \text{ V}$, $V_{DS} = 0$
	I_{GSS}	—	—	-10	μA	$V_{GS} = -10 \text{ V}$, $V_{DS} = 0$
Drain to source leak current	I_{DSS}	—	—	-1	μA	$V_{DS} = -20 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-0.4	—	-1.4	V	$V_{DS} = -10 \text{ V}$, $I_D = -1 \text{ mA}$
Drain to source on state resistance	$R_{DS(on)}$	—	219	280	m Ω	$I_D = -0.8 \text{ A}$, $V_{GS} = -4.5 \text{ V}^{\text{Note3}}$
	$R_{DS(on)}$	—	363	510	m Ω	$I_D = -0.8 \text{ A}$, $V_{GS} = -2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	$ y_{fs} $	1.3	1.9	—	S	$I_D = -0.8 \text{ A}$, $V_{DS} = -10 \text{ V}^{\text{Note3}}$
Input capacitance	C_{iss}	—	153	—	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	C_{oss}	—	37	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	31	—	pF	$f = 1 \text{ MHz}$
Turn - on delay time	$t_{d(on)}$	—	14	—	ns	$I_D = -0.8 \text{ A}$
Rise time	t_r	—	33	—	ns	$V_{GS} = -4.5 \text{ V}$
Turn - off delay time	$t_{d(off)}$	—	24	—	ns	$R_L = 12.5 \text{ } \Omega$
Fall time	t_f	—	8	—	ns	$R_g = 4.7 \text{ } \Omega$
Total gate charge	Q_g	—	2.2	—	nC	$V_{DD} = -10 \text{ V}$
Gate to source charge	Q_{gs}	—	0.5	—	nC	$V_{GS} = -4.5 \text{ V}$
Gate to drain charge	Q_{gd}	—	0.9	—	nC	$I_D = -1.6 \text{ A}$
Body - drain diode forward voltage	V_{DF}	—	-0.85	-1.1	V	$I_F = -1.6 \text{ A}$, $V_{GS} = 0^{\text{Note3}}$

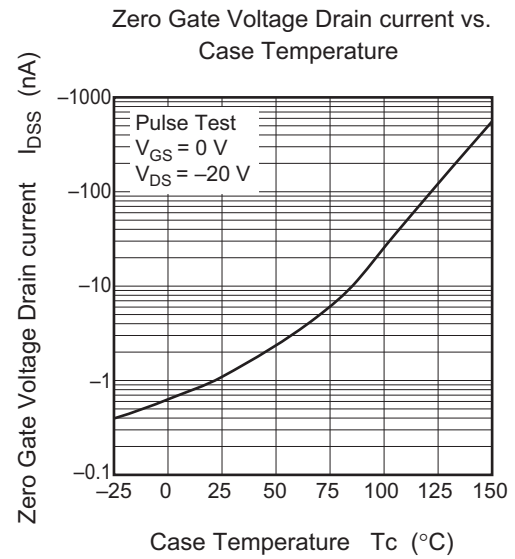
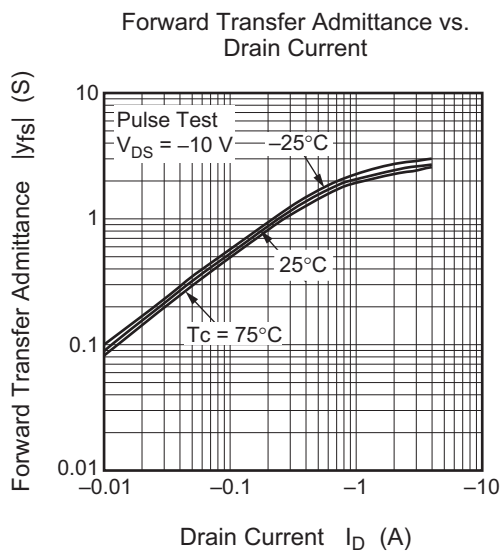
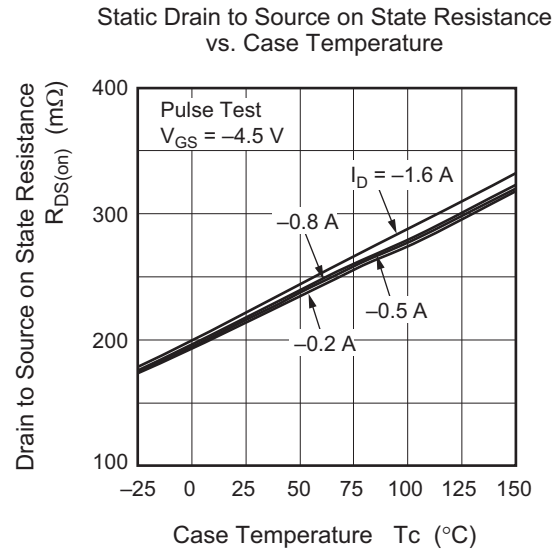
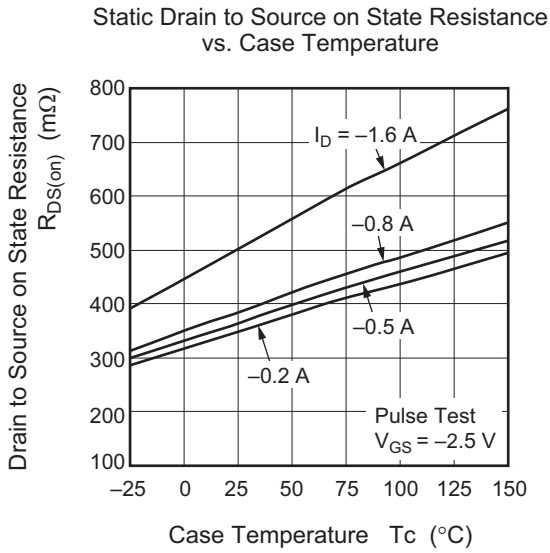
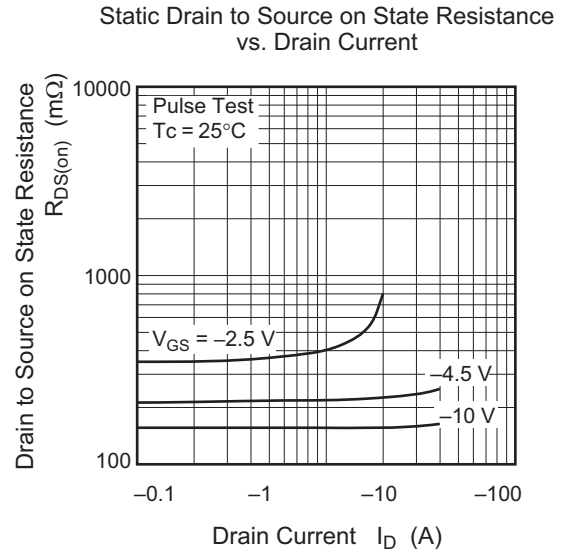
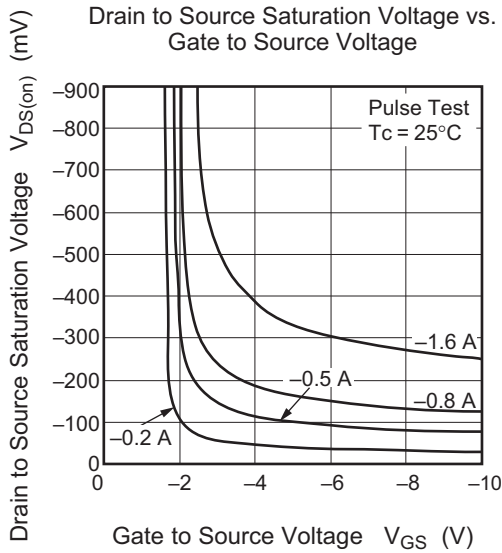
Notes: 3. Pulse test

Main Characteristics

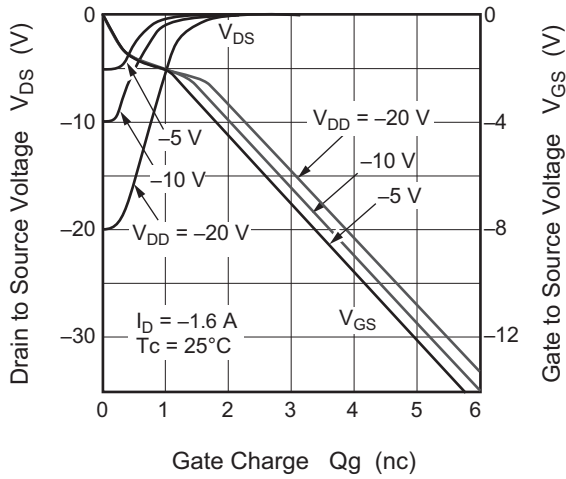


*When using the glass epoxy board (FR-4: 40 × 40 × 1 mm)

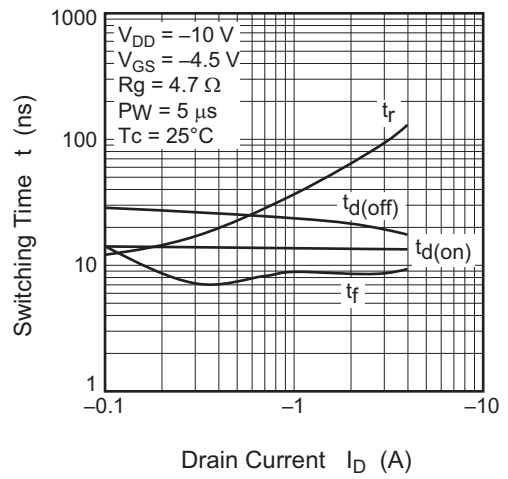




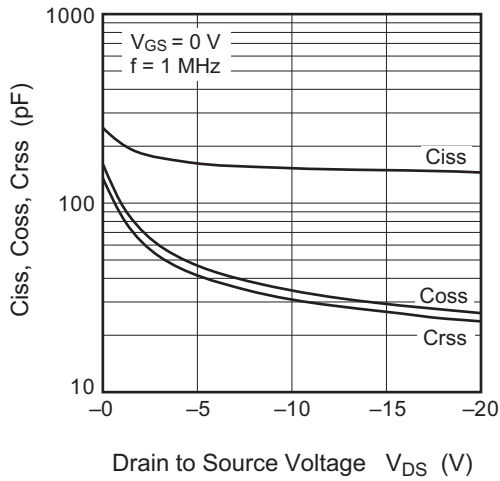
Dynamic Input Characteristics



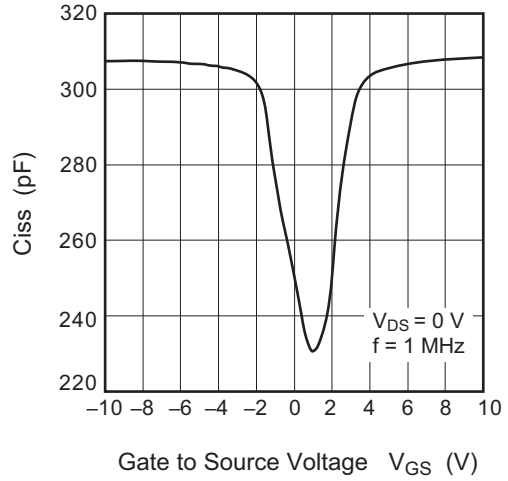
Switching Characteristics



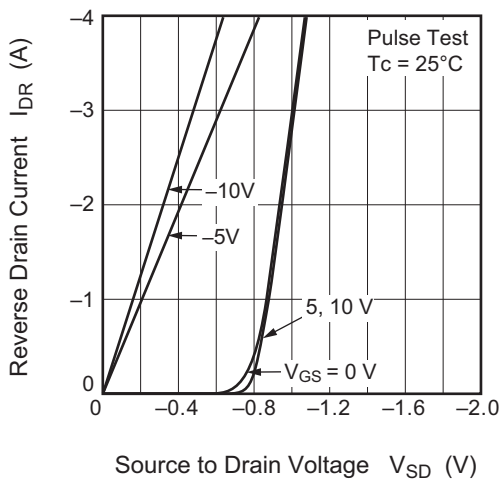
Typical Capacitance vs. Drain to Source Voltage



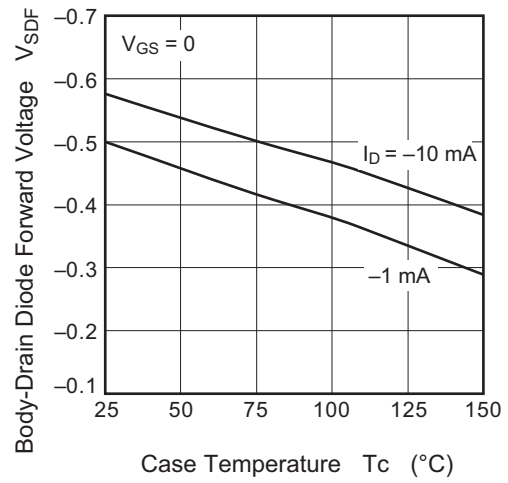
Input Capacitance vs. Gate to Source Voltage



Reverse Drain Current vs. Source to Drain Voltage

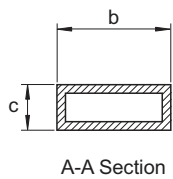
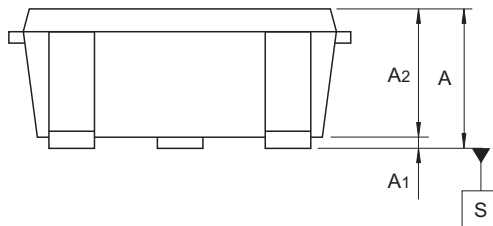
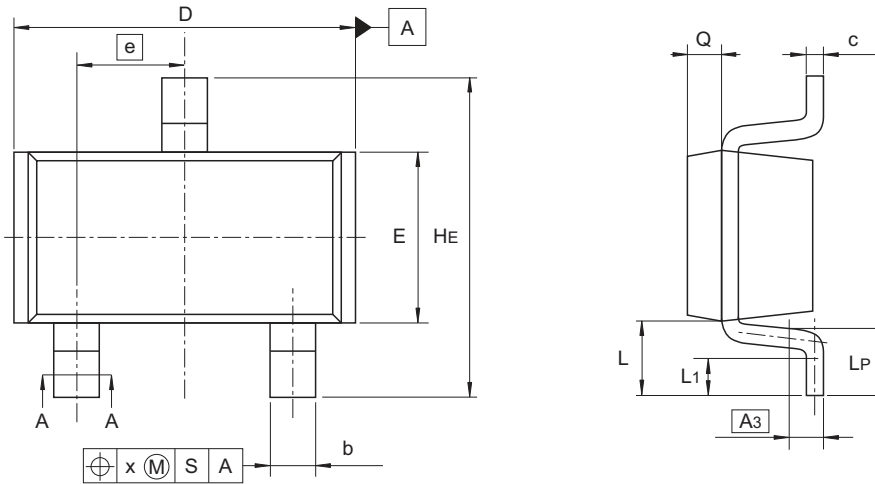


Body-Drain Diode Forward Voltage vs. Case Temperature



Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-59A	PLSP0003ZB-A	MPAK(T) / MPAK(T)V	0.011



Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
A	1.0	—	1.3
A1	0	—	0.1
A2	1.0	1.1	1.2
A3	—	0.25	—
b	0.35	0.4	0.5
c	0.1	0.16	0.26
D	2.7	—	3.1
E	1.35	1.5	1.65
e	—	0.95	—
HE	2.2	2.8	3.0
L	0.35	—	0.75
L1	0.15	—	0.55
LP	0.25	—	0.65
x	—	—	0.05
Q	—	0.3	—

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Orderable Part Number	Quantity	Shipping Container
RQJ0204XGDQATL-H	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

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2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-586-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 LanGao Rd., Putuo District, Shanghai, China
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

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Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
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